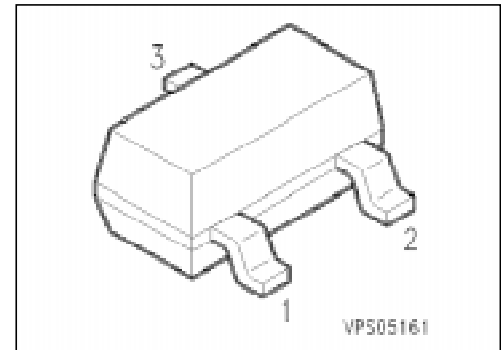


NPN Silicon RF Transistor

BF 799

- For linear broadband amplifier applications up to 500 MHz
- SAW filter driver in TV tuners



| Type | Marking | Ordering Code (tape and reel) | Pin Configuration | | | Package ¹⁾ |
|--------|---------|----------------------------------|-------------------|---|---|-----------------------|
| | | | 1 | 2 | 3 | |
| BF 799 | LK | Q62702-F935 | B | E | C | SOT-23 |

Maximum Ratings

| Parameter | Symbol | Values | Unit |
|---|-----------|----------------|------------------|
| Collector-emitter voltage | V_{CE0} | 20 | V |
| Collector-emitter reverse voltage | V_{CES} | 30 | |
| Collector-base voltage | V_{CB0} | 30 | |
| Emitter-base voltage | V_{EB0} | 3 | |
| Collector current | I_C | 35 | mA |
| Peak collector current | I_{CM} | 50 | |
| Peak base current | I_{BM} | 15 | |
| Total power dissipation, $T_A \leq 25 \text{ }^\circ\text{C}$ | P_{tot} | 280 | mW |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature range | T_{stg} | - 65 ... + 150 | |

Thermal Resistance

| | | | |
|----------------------------------|-------------|------------|-----|
| Junction - ambient ²⁾ | $R_{th JA}$ | ≤ 450 | K/W |
|----------------------------------|-------------|------------|-----|

¹⁾ For detailed information see chapter Package Outlines.

²⁾ Package mounted on alumina 15 mm × 16.7 mm × 0.7 mm.

Electrical Characteristics

at $T_A = 25\text{ °C}$, unless otherwise specified.

| Parameter | Symbol | Values | | | Unit |
|-----------|--------|--------|------|------|------|
| | | min. | typ. | max. | |

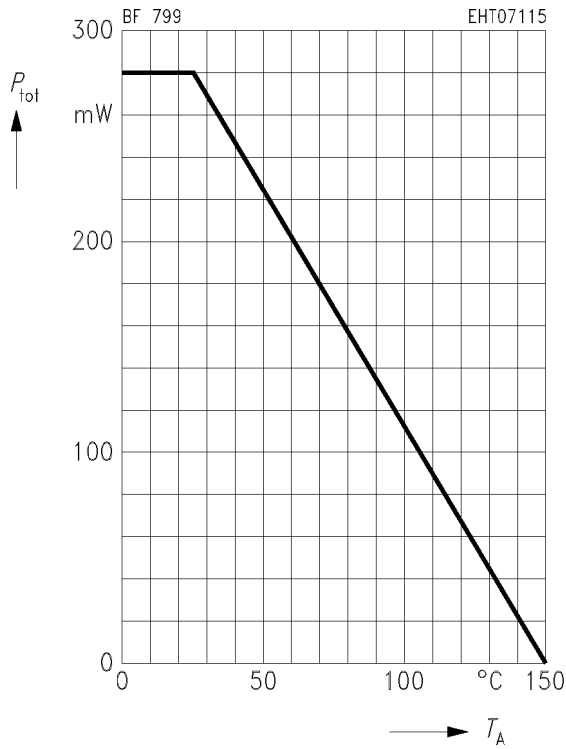
DC Characteristics

| | | | | | |
|--|----------------|----------|-----------|----------|----|
| Collector-emitter breakdown voltage $I_C = 1\text{ mA}, I_B = 0$ | $V_{(BR) CE0}$ | 20 | – | – | V |
| Collector-base breakdown voltage $I_C = 10\text{ }\mu\text{A}, I_E = 0$ | $V_{(BR) CB0}$ | 30 | – | – | |
| Emitter-base breakdown voltage $I_E = 10\text{ }\mu\text{A}$ | $V_{(BR) EB0}$ | 3 | – | – | |
| Collector cutoff current $V_{CB} = 20\text{ V}$ | I_{CB0} | – | – | 100 | nA |
| DC current gain, $V_{CE} = 10\text{ V}$ $I_C = 5\text{ mA}$ $I_C = 20\text{ mA}$ | h_{FE} | 35 40 | 95 100 | – 250 | – |
| Collector-emitter saturation voltage $I_C = 20\text{ mA}, I_B = 2\text{ mA}$ | $V_{CE sat}$ | – | 0.15 | 0.5 | V |
| Base-emitter saturation voltage $I_C = 20\text{ mA}, I_B = 2\text{ mA}$ | $V_{BE sat}$ | – | – | 0.95 | |

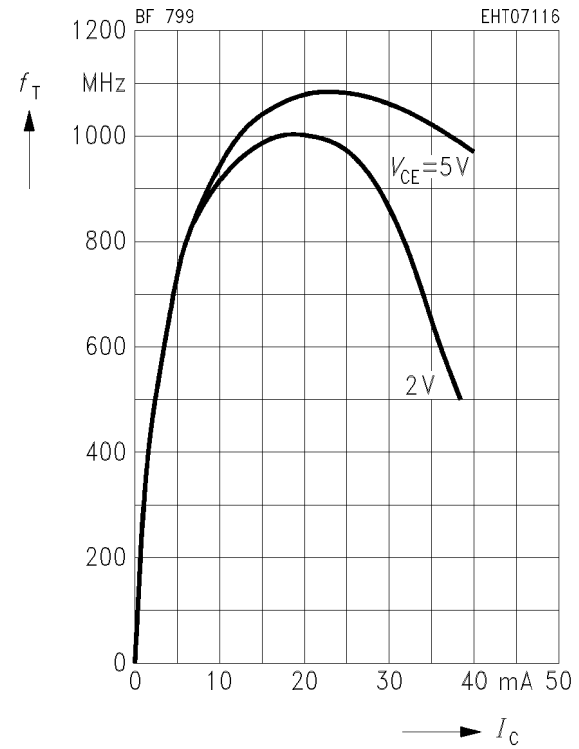
AC Characteristics

| | | | | | |
|--|-----------|--------|-------------|--------|---------------|
| Transition frequency $I_C = 5\text{ mA}, V_{CE} = 10\text{ V}, f = 100\text{ MHz}$ $I_C = 20\text{ mA}, V_{CE} = 8\text{ V}, f = 100\text{ MHz}$ | f_t | – – | 800 1100 | – – | MHz |
| Output capacitance $V_{CB} = 10\text{ V}, f = 1\text{ MHz}, I_E = 0$ | C_{ob} | – | 0.96 | – | pF |
| Collector-base capacitance $V_{CB} = 10\text{ V}, V_{BE} = 0\text{ V}, f = 1\text{ MHz}$ | C_{cb} | – | 0.7 | – | |
| Collector-emitter capacitance $V_{CE} = 10\text{ V}, V_{BE} = 0\text{ V}, f = 1\text{ MHz}$ | C_{ce} | – | 0.28 | – | |
| Noise figure $I_C = 5\text{ mA}, V_{CE} = 10\text{ V}, f = 100\text{ MHz}$ $R_S = 50\text{ }\Omega$ | F | – | 3 | – | dB |
| Output conductance $I_C = 20\text{ mA}, V_{CE} = 10\text{ V}, f = 35\text{ MHz}$ | g_{22e} | – | 60 | – | μS |

Total power dissipation $P_{tot} = f(T_A)$



Transition frequency $f_T = f(I_C)$ $f = 100 \text{ MHz}$



Collector-base capacitance $C_{cb} = f(V_{CB})$ $f = 1 \text{ MHz}$

